Plasma deposition and properties of composite metal/polymer and metal/hard carbon films

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Abstract - The growing interest in novel materials has promoted the investigation of two-component composite materials formed by small metal inclusions incorporated in an organic insulating medium. In this paper the recent knowledge of composite thin films composed of metal grains dispersed in the matrix of a plasma deposited polymer or a hard carbon is reviewed. The most important deposition techniques are presented and the relation between the deposition processes, the film microstructure and resulting film properties (especially optical and electrical) are discussed. The film characteristics are illustrated by the latest results from our laboratory.

INTRODUCTION

Over the past decade there has been a growing interest in the study of composite thin films because of the prospect to fabricate coatings with novel properties. At the beginning the main interest was in the systems composed of a metal and a metal oxide (or inorganic dielectric) which are sometimes called cerments (ref.1). However, in recent years growing attention has been paid to the composite systems which use as the dielectric phase an organic material - plasma polymer or hard carbon (refs. 2-4). Polymer films can be prepared by vacuum evaporation (ref.5), but sputtering and mainly plasma polymerization were applied in more cases (refs. 2-5). Generally, the passage of a glow discharge in an organic gas or a vapour results in the deposition of a polymer coating on exposed surfaces. Researchers usually tried to avoid contamination from the metal electrodes or other reactor components until they realized that the incorporation of metals into the matrix of a plasma polymer may lead to a new class of thin film materials (ref.6). Some of them became aware of the effect of energetic particle bombardment and UV light irradiation on the growth, structure and properties of resulting deposits. Obtained coating character changed from polymer, to hard polymer and, finally, to a - C:H or DLC (diamond-like) as the energy of bombarding positive ions was raised in the case of an r.f. glow discharge excited in a hydrocarbon gas or vapour (ref.7). In several very recent studies a metal has been supplied by thermal evaporation into the growing a - C:H film suggesting an improvement of properties of these metal/organic thin film systems (refs. 8-10).

In this review we discuss basic physical properties of the above mentioned metal/plasma polymer or metal/hard carbon composite films in connection with their deposition processes which use sputtering, sputter etching or thermal evaporation for a metal supply.

PLASMA DEPOSITION TECHNIQUES AND PROCESSES

Several methods using low temperature plasmas for the preparation of metal/plasma polymer or metal/hard carbon composite films in connection with their deposition processes which use sputtering, sputter etching or thermal evaporation for a metal supply.
The first two methods presented above became most popular. The schematic deposition arrangement can be seen in Fig. 1a. It is a plan-parallel plate electrode system with the earthed substrate holder and insulated target electrode powered from an rf generator (13.56 MHz) with one terminal grounded. Capacitive coupling of this electrode by means of a blocking capacitor causes development of substantial dc negative self bias ($U_D$) and therefore sputtering or reactive ion etching (or both) of the target (ref.28) providing thus a metal supply. The glow discharge which is excited by the mentioned target electrode in a monomer gas promotes plasma polymerization. Energetic electrons impact on monomer molecules in a gas phase and create a number of species. Free radicals are recognized of special importance as they are supposed to diffuse to the substrate where chain reactions, chains branching, terminations and crosslinking take place forming thus a solid polymeric component of the composite film (refs. 5, 29-31). If a planar magnetron is used as the excitation electrode (as shown in Fig. 1a) increased metal emission and plasma polymerization rates occur at the same power levels. Further increase of the metal emission may be achieved if we dilute a monomer using argon. In the discussed deposition arrangement (Fig. 1a) several halocarbon gases as CF$_3$, C$_2$F$_6$, C$_2$F$_3$Cl, C$_2$F, etc. (refs. 2-4, 32, 33) have been successfully used. However, when hydrocarbon or organosilicon gases are applied a "poisoning" of the target by a solid deposit often takes place hampering metal emission (refs. 34, 35). In this case it is more convenient to supply a metal from an ordinary evaporation boat and the target electrode use only for the discharge excitation as it is sketched in Fig. 1a. It has been shown that both ways of metal emission lead to equivalent composite films (ref.33).

Composite films grown on grounded or floating substrates are subjected to electron and ion bombardment and uv light irradiation. At usual discharge conditions floating or earthed substrate is negative against plasma potential (with the potential drop typically of the order of 10V). Positive ion bombardment with this average energy is of special importance as it enhances the plasma polymerization via production of surface free radicals (ref. 4). In the case of an ordinary planar magnetron mentioned the potential drop is lower and most of electrons are trapped by the tunnel magnetic field. The situation will change if we put an increased $U_D$ on the substrate via capacitive coupling of an independent rf generator or by splitting the original rf power. The most straightforward is to place the substrate on the excitation electrode (see Fig. 1b) - an idea suggested in the case of hydrocarbon plasmas by L. Holland (ref.7). When halocarbon gases are used...
competitive reactive ion etching takes place simultaneously. We did not ob-
serve any deposit on silica or glass substrates with CF₄ gas and deposition
turned into substrate etching when U₀ exceeded - 100 V. In the case of
C₂F₃Cl (chorotri fluoroethylene CTFE) (ref. 36). E. Kay (ref. 4) reported for
C₂F₃ that solid carbonaceous deposit covered the metal target up to U₀ =
-600 V. As it was mentioned above in the case of organosilicon or hydro-
carbon gases a solid polymeric coating was always obtained. Increasing U₀ in
the latter case one moves from a polymer to a hard polymer and finally to
a - C:H (DLC) film if U₀ exceeds - 200 V. These films possess unusual proper-
ties - high electrical resistivity, hardness higher than sapphire, optical
transparency in the infrared and chemical inertness. It has been suggested
that a - C:H film is composed of DLC (tetrahedral), graphite like (trigonal)
and polymeric components and voids. Considerable amount of hydrogen is trap-
ped and bonded in the film (up to 25%) (refs. 8, 38, 39). In order to reduce
the amount of hydrogen we have used a mixture of CTFE with benzene at U₀ =
-180 V and observed that the deposition rate increased reaching peak at
70%. However, hard a - C:H films changed into predominantly polymeric soft
coatings (ref. 36, 40). The same results obtained Sah (ref. 40) using fluorini-
ated benzenes. Memming has shown recently by means of IR spectroscopy
structural differences between hard polymer and a - C:H films (ref. 41). More
details about a - C:H films may be found in the latest reviews (e.g. refs.
42, 43).

A metal can be simply incorporated into a growing a - C:H film by thermal
evaporation (see Fig. 1b). In this way we have prepared composite metal/a -
C:H films with metals as Au, Ag, Al and Cu (refs. 9-11, 36). Weissmantel
et al (refs. 8, 12, 13) have used instead of usual rf diode system an ion
plating system operating at 0.1 Pa in benzene and metals as Cr, Al and Ti
were co - evaporated.

A dc post cathode cylindrical magnetron was used for reactive sputtering of
stainless steel cathode in Ar/C₂H₆ mixture (refs. 14-16) and this study was
completed using planar magnetron. The authors suggested that cathode was
first covered with a - C:H which was subsequently sputtered off. The necessa-
ry bombardment of the layer growing on the substrate at a floating potential
came from energetic neutrals reflected from the cathode. Nickel/carbon films
were also prepared by dc reactive sputtering in an Ar/CH₄ mixture in an
diode system (ref. 17). Weissmantel et al. (ref. 13) have also reported me-
tal/hard carbon films prepared by magnetron co-sputtering of graphite and Ti
or Sn metals. Savvides and Window (ref. 44) announced "DLC films" prepared
by magnetron sputtering of graphite using unbalanced planar magnetron. They
claimed that the escaping beam of the discharge plasma (negative glow) cau-
sed negative biasing of the substrate and the growing deposit and attracted
positive ion bombardment (up to 40 eV energy). Using such unbalanced planar
magnetron in the geometrical set-up similar to that pictured in Fig. 1a me-
tal hard/carbon films were deposited (ref. 18). Composite metal/graphite
target was sputtered in Ar or Ar/propane mixture. Most of the attention has
been paid to silver, but Au, Mo, Pt and Cu have also been examined.

As a great number of parameters influence the deposition procedure the depo-
sition processes should be in situ monitored using a diagnostic technique.
The optical emission spectroscopy is the simplest one. A convenient metal li-
ne is compared to a nearby positioned argon line or the intensity of the e-
mision band of a typical radical. An example may be gold line at λ = 267
nm compared to the height of the band head belonging to the CF₃ radical at
λ = 265 nm in the case of gold/plasma polymerized (pp) fluoro-carbon films
(ref. 45). More optical techniques are available e.g. actinometry etc. Mass
spectroscopic techniques are very useful, e.g. quadrupole mass spectrometer
as it was applied by E. Kay and his co-workers (ref. 4). Electric probe mea-
surements are also very helpful in laboratory experiments (ref. 46) but dif-
ficult to be placed permanently into the production apparatus.

COMPOSITE FILM STRUCTURE

Metal/plasma polymer films

The composite film structure develops as a result of competitive processes of
polymer formation and metal nucleation on the substrate surface. In principle,
without the individual deposition rates of both constituents but in fact the problem is very complex and many effects play an important role:
sticking probability for individual species, surface migration in dependence
on the actual surface temperature and specie energy, chemical reactivity, in-
ternal stresses etc.
Although various metal-polymer combinations were examined (pp CF/Co, Mo, Cu (ref. 47), co-sputtered Ekonol/Au system (refs. 23, 48), coevaporation of polyethylene/Cu (ref. 27)) most effort has been devoted to the structural analysis of gold-containing halopolymers (refs. 4, 20, 32, 33, 47-49, 50-52). The film microstructure was studied systematically on pp CF/Au (refs. 4, 47-49) and pp CTFE/Au (refs. 50-52) composite systems. Increasing the gold volume fraction \( f \) in the layers grown on non-thermostated substrates by applying an increasing power \( (\text{and } U_p) \) to the planar magnetron covered by a gold target led to an increase of gold grain diameters from 10 nm to above 100 nm at \( f = 0.52 \) (Fig. 2). An important structural feature in this case is the presence of a system of smaller grains dispersed among the larger irregular particles that will play an important role during the post-annealing treatment.

The effect of the substrate temperature on the size of the metal clusters was clearly demonstrated in refs. 4, 48-49. The change of the substrate temperature during the deposition from -10°C to 60°C resulted in a substantial increase in the grain diameters. Also the post-annealing above the temperature of the main (glass-rubber) transition in the polymeric constituent at about 160°C (refs. 4, 48, 49, 53) caused considerable increase in the grain sizes including spheroidization, coalescence and sintering of the gold clusters due to enhanced motion and migration radius of the small incorporated metal particles. The diffraction analysis (ref. 4) indicated a texturing in the (111) direction of the Au crystallites formed at room temperature. Annealing to 200°C causes a decrease in the texturing due to a coalescence of small particles to large aggregates of twinned crystal clusters.

The composition and chemical structure of the Au/halopolymer systems was extensively studied in dependence on the preparation parameters and possible plasma surface interactions (refs. 4, 33, 48, 51). The most important result is the decrease in the halogen atom concentration when the gold volume fraction is increased as documented by AES depth profile analysis of the films (Fig. 3), infrared spectroscopy (Fig. 4) as well as by ESCA (ref. 48).

Usually, during the surface analysis (AES, ESCA etc.) the interpretation of results is to be carried out very carefully because of the actual surface modification by the applied agent (ions, electrons, photons) causing preferential sputtering, especially in the case of organic materials. Therefore, only relative changes in the film composition analysed by the same treatment are expected to yield reliable information (ref. 54).

The higher gold content in the layers is accompanied by the decrease in the halogen concentration (refs. 48, 50, 51) and the more pronounced differences between the surface and the bulk composition (refs. 33, 50, 51) (Fig. 3). The overall losses of fluorine from the layers are documented by the shift in the infrared spectra of the band due to CF\(_2\) stretching vibrations at 1210 cm\(^{-1}\) to CF\(_2\) stretching centered at 1100 cm\(^{-1}\) (Fig. 4). These effects were explained by enhanced bombardment of the layers during the film growth. The energetic species striking the surface modify especially the polymer constituent (preferential losses of halogens), enhance the surface chemical reactivity (film surface vs. bulk differences) and indirectly support the increase in the gold grain diameters and surface roughness (refs. 50, 52).
It has been hypothesized, that the negative (predominantly gold) ions accelerated from the negatively biased powered electrode play the decisive role in this respect (refs. 23, 33, 50, 51). The occurrence of such negative ions has been anticipated after direct measurements of the sputter-deposition of various gold-containing intermetallic compounds and a simple model for negative gold ion formation based on a difference between the ionisation potential and the electron affinity of atoms at the target surface (ref. 55). The enhanced formation of negative ions at the presence of a gold target has been confirmed by Langmuir probe measurements in our deposition system (Fig. 5) (ref. 56). The decrease of the electron saturation current after addition of CTFE to Ar clearly signifies the formation of negative ions. A preliminary analysis has disclosed that the concentration of negative ions in the plasma is of the same order as the concentration of electrons. It is evidenced from Fig. 5.

Fig. 3. AES elemental concentration depth profiles of pp CTFE films containing various gold volume fractions f.

Fig. 4. IR absorption spectra of pp CTFE films containing various gold volume fractions.

Fig. 5. Probe current I versus probe voltage U_p with respect to the plasma potential for various Ar/CTFE working gas mixtures and for aluminium --- and gold —— targets.
that n, is substantially higher at the presence of a gold target than in the system with an aluminium one.

Since the metal/plasma polymer films grow under nonequilibrium conditions the structural instabilities are usually inherently present and estuary in considerable aging effects at ambient atmosphere (ref. 57). In this respect the presence of incorporated free radicals and subsequent coalescence of small metal particles is important. Substantial stabilisation may be reached by vacuum post-annealing to about 80°C for 30 min in the case of ppCTFE/Au systems.

Metals/a-C:H films

Although a number of vacuum methods and sophisticated treatments for deposition of carbonaceous films have been applied, the resulting film structure is affected entirely by a single parameter - the energy flux carried by the species impacting on the growing insulating layer at the presence of a hydrocarbon gas or vapour. The plasma deposited carbon films were usually found to be amorphous (e.g. refs. 38, 58, 59) but partly a polycrystalline diamond structure has also been reported (e.g. refs. 60, 61). A model of the microstructure has been suggested (ref. 12) consisting of puckered n-fold (n = 3-8) rings interconnected by strong cross-links involving tetrahedral bonds. Using an effective medium approach (ref. 37) the as-deposited films were found to contain amorphous diamond-like, amorphous graphitic and polymeric components. Upon annealing the amorphous diamond-like and polymeric components decrease, the graphitic part grows and a void component appears.

In view of further modifications of the film characteristics various metals have been incorporated into the a-C:H matrix. Cr/a-C:H and Al/a-C:H systems were prepared (refs. 8, 12) in an ion plating arrangement. A decrease in the hardness when the metal fraction is increased has been observed. The diffraction data suggested that carbon atoms are incorporated between individual metal atoms of tetrahedra. After annealing above 350°C aggregation of metal crystals containing the carbides was observed. The Al/a-C:H films exhibited the Al:C composition with x varying from 0.2 to 0.6. However, mechanical or thermal treatment caused fast decomposition.

Extensive work has been devoted to the investigation of metal-carbon films for solar selective absorbers (refs. 14-16). Reactive sputtering of Cu and stain-less steel was performed in C₂H₆ and CH₄ gases. The metals were bonded predominantly in corresponding carbide forms:

In our laboratory Al, Cu, Ag, Ni and Au were added by evaporation into the a-C:H films grown on the excitation rf powered (negatively biased) electrode at the presence of benzene or butane (refs. 36, 10). Au, Ag and Cu were dispersed in the form of nearly spherical metal clusters (3-10 nm in diameter) in the amorphous carbon matrix. Further spheroidization of the metal grains after annealing to 200°C has been observed.

When increasing the metal volume fraction the hardness of these films subsequently decreased. A typical example is shown in Fig. 6 for a Ag-doped a-C:H film grown at 40 W (-500 V bias) and 1 Pa in of the Ar (30%)/butane working gas mixture.

The stability of the structure and properties were found to be much better and the aging effects much less important than in the case of metal-containing plasma polymers.

![Fig. 6. The Vickers microhardness Hᵥ (kg/mm²) as a function of increasing silver volume fraction characterized by the I(Ag)/I(Ar) emission line intensity ratio.](image-url)
OPTICAL PROPERTIES

Metal/plasma polymer films

In the case of metal-containing plasma polymers the anomalous optical absorption in the visible region occurs (similarly to cermets - ref. 63) that gives rise to a spectral selectivity and coloured appearance of the films. Most data have been reported on gold-doped halocarbon plasma polymers (refs. 20,32,33,47,48,50,52,64). When increasing the metal volume fraction \( f \) an absorption maximum develops near 550 nm (ref. 64). With higher \( f \) this maximum systematically shifts to longer wavelengths and the transmission at higher \( \lambda \) subsequently decreases. According to \( f \) various film colours may be distinguished: \( f \sim 0.01 \) - pink, \( f \sim 0.06 \) - red, \( f \sim 0.24 \) - violet, \( f \sim 0.37 \) - blue.

The optical properties with emphasis on the colour effects have been reported also for other polymer/metal combinations: HMDS/Al (ref. 21), DF/Cu, Al (ref. 20), DMTS, HMDS/Ag,Au,Cu (ref. 63). However, when films are prepared in a reactive gas atmosphere using a chemically active metal dopant, the tinting can be caused by the optical absorption due to the originated chemical compounds (ref. 66).

After annealing the gold-halocarbon polymer films, the optical characteristics usually dramatically change (refs. 48,64). Depending on the value of \( f \), the absorption maximum may change its form (become deeper and narrower) and position. Simultaneously, the transmission at longer wavelengths may decrease or increase according to the microstructural rearrangement responsible for these effects. Two main structural events play decisive role in this respect: losses of the polymer phase at increased temperatures and, more efficiently, the changes in the grain shape and size (spherodization, coalescence etc.). Pronounced changes were observed when the temperature was increased above its critical value that coincides with the main transition in the polymer - about 160°C in the case of pp fluorocarbon polymers (refs. 48,53). Nevertheless, also spontaneous changes in the optical characteristics during the aging of the films after the deposition have been observed (ref. 57). In this case the coalescence of the metal grains is dominant as has been shown experimentally (TEM) as well as by the theoretical effective medium approach.

Effective medium (EM) approach

Independently, the EM theory has been applied to the study of gold-containing halocarbon plasma polymers in two laboratories (refs. 48,52,67). The EM approach is principally based on two assumptions (ref. 68): i) The inhomogeneities are so large that each point in the material can be associated with the macroscopic dielectric function; ii) The system can be described as an EM if the random unit region, embedded in the EM, is not detectable in an experiment using electromagnetic radiation confined to a specified wavelength range. It means that the extinction of the random unit region should be the same as if it were replaced by a material with an effective dielectric function.

The condition that the inhomogeneities are substantially smaller than the wavelength of light is usually fulfilled in the case of plasma deposited composite metal-containing plasma polymers. In refs. 52,67 four models of an EM have been tested to simulate the optical behaviour of Au/ppCTFE systems: 1) the Maxwell-Garnett (MG) model (ref. 69) for topologically asymmetric composites, 2) the Bruggeman self-consistent (BSC) model (ref. 70) for topologically symmetric systems, 3) the "correlated three component system" (CS) (ref. 71) being an extension of the BSC theory, and, finally, 4) the probabilistic growth (PG) model (ref. 72) incorporating the advantages of both the MG and BSC theories.

The comparison of the experimentally obtained optical responses and theoretical predictions is illustrated in Fig. 7, when spherical grain shapes are considered. It has been shown that the PG model yields the best fit with the experiment within \( f \) up to 0.52. The PG model predicts the position and the absolute values of the maxima in \( n \) and \( k \) in the resonance region at lower \( f \) and simulates also an increasing extinction in the infrared region at higher \( f \). On the other hand the MG model partly fits at low \( f \) (\( \leq 0.3 \)) but it fails at higher \( f \).

The optical transmission of gold-doped pp C\(_2\)F\(_6\) films has been simulated by generalized PG and MG models for ellipsoidal particle shapes (ref. 48). Agreement of the theoretical predictions based on the PG model with experimental values was obtained for as deposited as well as annealed samples. The observed broadening of the resonance peak was partially explained by considering the
topological disorder. A three phase model based on the PG theory was proposed that could explain the possible existence of a carbon layer at the gold - - PPTFE interface as suggested by XPS analysis, but no distinct correspondence to the optical behaviour has been obtained.

The position of the experimental dielectric function of gold-doped ppCTFE has been studied with respect to the absolute limits (Wiener bounds) in the complex plane (ref. 52). An application of such approach for direct estimation of microstructural parameters from optical measurements has been suggested (ref.73).

Metal/a-C:H films

In contrast to plasma polymers that possess very low absorption in the visible region so that the imaginary part of the dielectric function is negligible, the carbon films exhibit higher absorption. In numerous studies the absorption coefficient - $\alpha$ - of a - C:H films has been measured as a function of experimental conditions - post-annealing (ref.74), CTFE concentration in the CTFE/benzene working gas mixture (ref.86) or the substrate negative bias voltage (ref.36). By plotting $(\alpha k l)^{1/2}$ versus the photon energy $h\omega$ the optical gap may be evaluated.

The effect of metal inclusions on the optical behaviour of a - C:H films has been recently studied in our laboratory. Typical transmission spectra of Ag-doped a - C:H films are shown in Fig. 8, when the Ag concentration is subsequently increased. With the growing Ag content the transmission in the near UV rises but decreases at longer wavelengths. An absorption maximum develops around 400 nm and shifts to longer $\lambda$ as the amount of Ag is increased.
ELECTRICAL PROPERTIES

Composite metal/plasma polymer films

Boonthanom and White (ref. 27) measured composite copper/polyethylene films prepared by vacuum co-evaporation. The electrical characteristics of as-deposited films exhibited instabilities so in situ annealing up to 493 K was performed. This procedure converted Cu into CuO islands. If the temperature of 423 K was only reached the centres of Cu remained in oxide islands. Hopping of electrons between traps in localized states close to the Fermi level was considered as a conduction mechanism.

The electrical properties of Au/pp halocarbon films were studied by Perrin et al. (ref. 49) and simultaneously in our laboratory (refs. 67,75). If one considers the dependence of dc conduction versus volume fraction, first, low value is observed as the transport processes are basically governed by electron tunneling between the gold grains. Percolation threshold is reached at a volume fraction $f_c \sim 0.4$ and conductivity phenomena become more complex. In ref. 49 in accord with usual cermet film approach the effective medium theory after Ping Sheng was shown to describe correctly the conductivity above $f_c$. The effect of annealing on film resistivity has been studied in the case of gold doped pp CTFE (refs. 67,75). Above 80°C the irreversible changes of the sheet resistance were observed documenting the commence of the microstructural rearrangement. The temperature dependence of the sheet resistance in the case of Au/ppCF$_4$ is in Fig. 9 (ref.75). The most dramatic change above percolation threshold seems to start at about 150°C. This points out the fact that polymer component approaches glass transition temperature which is likely below 200°C as indicated in ref. 53. The decrease of resistivity for samples with the volume fractions above $f_c$ after annealing at 180°C was also observed in ref. 49. TEM observations revealed the increase of the island sizes and their coalescence especially for higher gold concentration.

As far as the ac behaviour is concerned several works on pure plasma polymers have been published (refs. 53,76,77,78). Considerable influence of oxygen and water vapour after the films are exposed to the atmosphere were reported. When metal was incorporated additional conductivity component appeared (refs. 4,77). A careful study of composite films ac behaviour and the influence of ambient atmosphere would be beneficial. Similar electrical properties of co-sputtered composite films have been found in ref. 23.
Composite metal/hard carbon films

The electrical properties of plain a-C:H films have been measured by several authors (see refs. 42,79). Jones and Stewart (ref.79) have found that conductivity of their a-C:H films decreases with the monomer used in following order: methane, ethane, acetylene and ethylene and substrate temperature. Pressure in the reactor was 0.13 torr, flow rate 3-6 cm$^3$ STP/min and $U_B = -380$ V. Phosphine, diborane and nitrogen gases have been mixed into monomer in known small amounts. The specimen conductivity increased by one and three orders of magnitude, depending on the substrate temperature. Conduction is predominantly by hopping in a region of high density of localized states for both doped and undoped samples. Doping or increased substrate temperature modified density of localized states in a way that moved the conduction path closer to the Fermi level fixed with respect to valence band. Therefore, it was suggested that doping did not take place substitutionally, as for amorphous silicon but increased the density of localized states.

In our laboratory we have studied Au and Ag/ a-C:H films. The irreversible change of resistivity occurred at temperatures between 200 and 250°C in the former case and above 250°C in the latter case. The TEM observations of these films revealed only minor changes after the annealing except that metal islands obtained more spherical shapes. It seemed that for the increased conductivity a structural change of a-C:H component of the composite was responsible. Sikkens (ref. 17) found for his co-sputtered Ni/hard carbon films that the electrical resistivity changed only a little after 2 hours annealing at 400°C. Weissmantel et al. (ref. 13) have also measured dc conductivity of Ti or Sn/hard carbon sputtered films as as a function of metal volume. Biederman et al.(ref.18) found instabilities in the electrical properties of Ag/hard carbon sputtered films caused by aging effects.

![Fig. 10. The resistance R of a gold-containing a-C:H film versus temperature T (working gas mixture: Ar/butane, 3 Pa, $U_B = -500$V, 40W rf power). The subsequent annealing cycles: temperature increase: ● △ ● and decrease: ▽.](image)

CONCLUSIONS

Deposition processes and basic physical properties of both-composite metal plasma polymer and metal/hard carbon films have been briefly reviewed from the present state of knowledge. Several applications have been proposed. Let us mention few examples. In optics the discussed films were suggested as large area optical filters or decorative coatings (ref. 21) and for optical recording (refs. 80,81). In microelectronics (VLSI technology) Morita and Hat-tori described dry lithography involving an X-ray mask from gold doped pp styrene (ref. 82). Metal/hard carbon films were suggested for improvement of electrical contacts (ref. 13). However, there are still several problems in the production of the discussed films and their post-deposition behaviour which have to be fully understood before wider application will be possible.
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